International

SCHOTTKY RECTIFIER

Major Ratings and Characteristics

MBRD650CT MBRD660CT

6 Amp

I_{F(AV)} = 6.0Amp V_R = 50-60V

Units Characteristics Values I_{F(AV)} Rectangular 6 А waveform 50-60 V V_{RRM} I_{FSM} @ tp = 5 µs sine 490 А @3Apk, $T_J = 125^{\circ}C$ V_F 0.65 V (per leg) -40 to 150 °C T_J range

Description/ Features

The MBRD650CT, MBRD660CT surface mount, center tap, Schottky rectifier series has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Popular D-PAK outline
- Center tap configuration
- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



Document Number: 93463

MBRD650CT, MBRD660CT

Bulletin PD-20755 rev. E 05/06

International

Voltage Ratings

| Part number | MBRD650CT | MBRD660CT |
|--|-----------|-----------|
| V _R Max. DC Reverse Voltage (V) | 50 | 60 |
| V _{RWM} Max. Working Peak Reverse Voltage (V) | | |

Absolute Maximum Ratings

| | Parameters | Value | Units | Conditions | |
|--------------------|------------------------------------|-------|-------|---|---|
| I _{E(AV)} | Max. Average Forward (Per Leg) | 3.0 | A | 50% duty cycle @ T _c = 128°C, r | ectangular wave form |
| . (, | Current * See Fig. 5 (Per Device) | 6 | | - | |
| I _{FSM} | Max. Peak One Cycle Non-Repetitive | 490 | Α | 5µs Sine or 3µs Rect. pulse | Following any rated load condition and with |
| | Surge Current * See Fig. 7 | 75 | | 10ms Sine or 6ms Rect. pulse | rated V _{RRM} applied |
| E _{AS} | Non-Repet. Aval. Energy (Per Leg) | 6 | mJ | $T_{J} = 25 \degree C, I_{AS} = 1 \text{ Amp}, L = 12 \text{ mH}$ | |
| I _{AR} | Repetitive Avalanche Current | 0.6 | A | Current decaying linearly to zer | |
| | (PerLeg) | | | Frequency limited by $T_J max. V_j$ | = 1.5 x V _R typical |

Electrical Specifications

| | Parameters | Value | Units | Conditions | |
|-----------------|-------------------------------------|-------|-------|--|--|
| V _{FM} | Max. Forward Voltage Drop | 0.7 | V | @ 3A T ₁ = 25 °C | |
| 1 101 | (Per Leg) * See Fig. 1 (1) | 0.9 | V | @ 6A 1 _J = 23 C | |
| | | 0.65 | V | @ 3A | |
| | | 0.85 | V | @ 6A T _J = 125 °C | |
| I _{RM} | Max. Reverse Leakage Current | 0.1 | mA | $T_{J} = 25 \text{ °C}$ $V_{p} = \text{rated } V_{p}$ | |
| | (Per Leg) * See Fig. 2 (1) | 15 | mA | $T_J = 125 \text{ °C}$ | |
| CT | Typ. Junction Capacitance (Per Leg) | 145 | pF | V_R = 5 V_{DC} (test signal range 100Khz to 1Mhz) 25°C | |
| L _S | Typical Series Inductance (Per Leg) | 5.0 | nH | Measured lead to lead 5mm from package body | |
| dv/dt | Max. Voltage Rate of Change | 10000 | V/µs | (Rated V _R) | |

(1) Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications

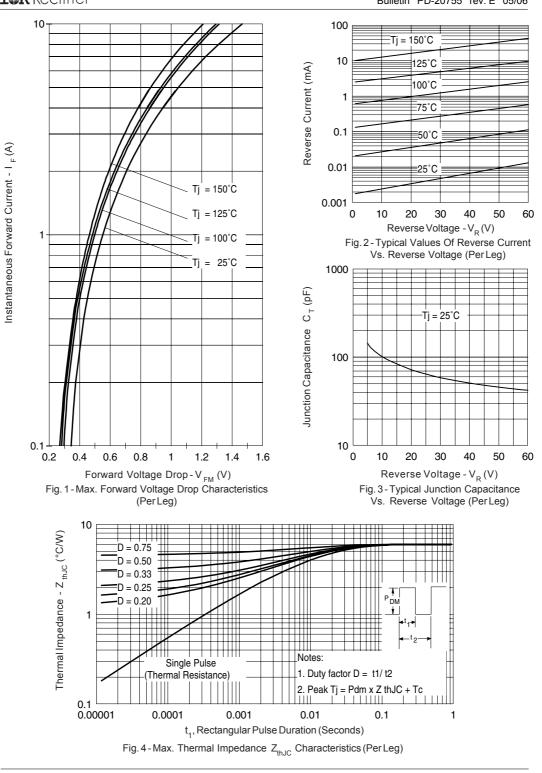
| | Parameters | | Value | Units | Conditions |
|-------------------|-------------------------------------|--------------|------------|--------|---------------------------|
| TJ | Max. Junction Temperature Range (*) | | -40 to 150 | °C | |
| T _{stg} | Max. Storage Temperature Range | | -40 to 150 | °C | |
| R_{thJC} | Max. Thermal Resistance | (PerLeg) | 6 | °C/W | DC operation * See Fig. 4 |
| | Junction to Case | (Per Device) | 3 | | |
| R _{thJA} | Max. Thermal Resistance J | unction | 80 | °C/W | |
| | to Ambient | | | | |
| wt | Approximate Weight | | 0.3 (0.01) | g(oz.) | |
| | Case Style | | D-Pa | k | Similar to TO-252AA |
| | Device Marking | | MBRD66 | 50CT | |

 $\frac{(^{*})}{dTj} \frac{dPtot}{dTj} < \frac{1}{Rth(j-a)} \quad \text{thermal runaway condition for a diode on its own heatsink}$

Document Number: 93463

International

MBRD650CT, MBRD660CT Bulletin PD-20755 rev. E 05/06



Document Number: 93463

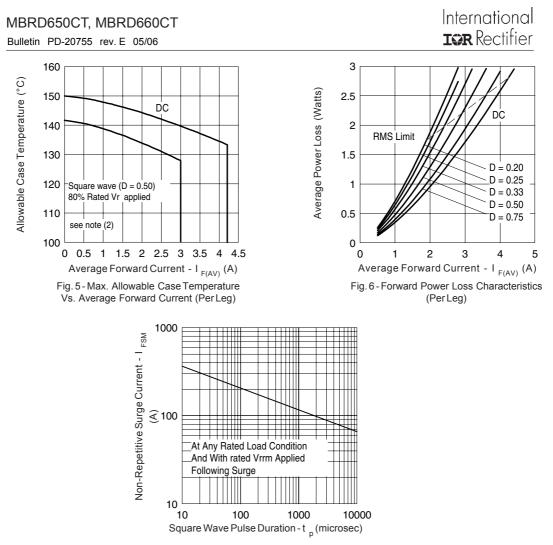


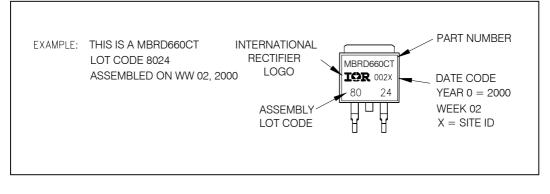
Fig. 7 - Max. Non-Repetitive Surge Current (Per Leg)

(2) Formula used: $T_{C} = T_{J} - (Pd + Pd_{REV}) \times R_{thJC}$; Pd = Forward Power Loss = $I_{F(AV)} \times V_{FM} @ (I_{F(AV)}/D)$ (see Fig. 6); Pd_{REV} = Inverse Power Loss = $V_{R1} \times I_{R} (1 - D)$; $I_{R} @ V_{R1} = 80\%$ rated V_{R}

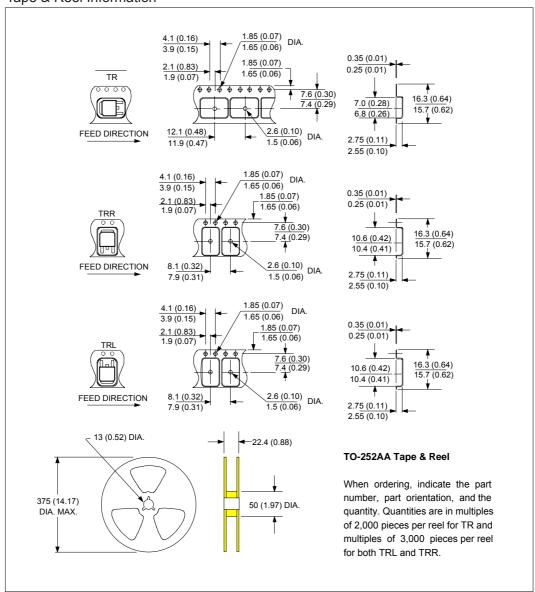
Document Number: 93463

Outline Table L3 & b3 ES Ç MOLD FLASH SHALL NOT EXCEED .005 [0.13] F BASE WETAL ONLY. D AT DATUM PLANE H. TUNE TO-252AA. NOTATED BOT CH SCALE 201 N C HES .094 .095 .035 .035 .031 .045 .024 .022 .035 .245 -.265 ġ MAx, 2.39 0.13 0.89 0.79 1.14 5.46 0.61 0.56 0.89 6.22 -6.73 Vill, 2,18 -0,64 0,65 0,76 4,95 0,46 0,41 0,46 5,97 5,21 6,35 4,32 2,29 9,40 Min. .086 -.025 .025 .030 .195 .018 .018 .235 .205 .250 .170 L A A1 b b b b b c c1 c2 D D1 E E1 e H L L1 L2 L3 L4 L5 e e1 e2 7 LEAD AS 6 4 6 HEXFET 1.- GATE 2.- DRAIN 3.- SOURC 4.- DRAIN .09 10.41 1.40 2.74 0.51 0.89 -1.14 0' 0' 25' BSC 1.27 1.02 1.52 10* 15* 35* .02 .035 -.045 0 0 25 .050 .040 .060 10* 15* IGBT & CoF 由 ₹ ₿ 1.- GATE 2.- COLLECTOR 3.- EMITTER 4 - COLLECTOR Modified JEDEC outline TO-252AA Dimensions in millimeters and (inches)

Part Marking Information



Document Number: 93463



Tape & Reel Information

Document Number: 93463

| Device Code | MBR D 6 60 CT TR - 1 2 3 4 5 6 7 |
|-------------|--|
| | Schottky MBR Series D = D-Pak (TO-252AA) Currrent Rating (6 = 6A) Voltage Ratings Voltage Ratings CT = Center Tap (Dual) O = 60V Onone = Tube (50 pieces) TR = Tape & Reel TRL = Tape & Reel (Left Oriented) TRR = Tape & Reel (Right Oriented) TRR = Tape & Reel (Right Oriented) O = 000 |

Ordering Information Table

Data and specifications subject to change without notice. This product has been designed and qualified for AEC Q101 Level. Qualification Standards can be found on IR's Web site.

International

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Document Number: 93463



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